

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of		)
		)
	Toshiki Makimoto, et al.	)
		)
Serial No.:	10/516,380	) Art Unit
		) 2818
Filing Date:	November 30, 2004	)
		)
Confirmation No.:	2860	)
		)
For:	P-TYPE NITRIDE SEMICONDUCTOR	)
	STRUCTURE AND BIPOLAR TRANSISTOR	)
		)
Examiner:	Tram Hoang Nguyen	)

AMENDMENT "B" AND RESPONSE TO FINAL OFFICE ACTION

Commissioner for Patents  
PO Box 1450  
Alexandria, Virginia 22313-1450

Examiner:

Applicant submits this paper in response to the Final Office Action mailed July 11, 2007 and in conjunction with a Request for Continued Examination (RCE). Reconsideration is respectfully requested in view of the following remarks:

**Amendments to the Claims** begin on page 2 of this paper.

**Remarks** begin on page 5 of this paper.